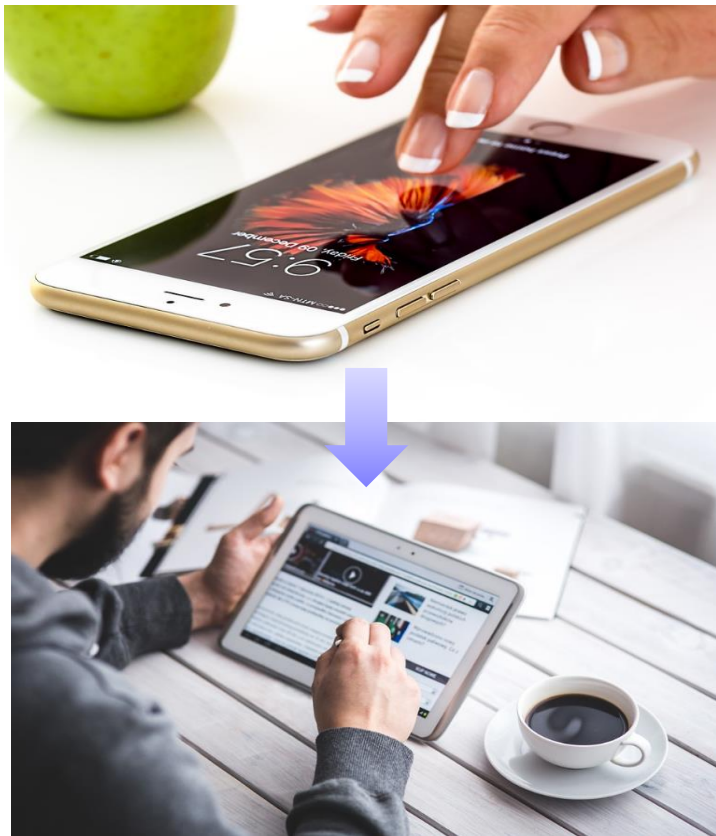


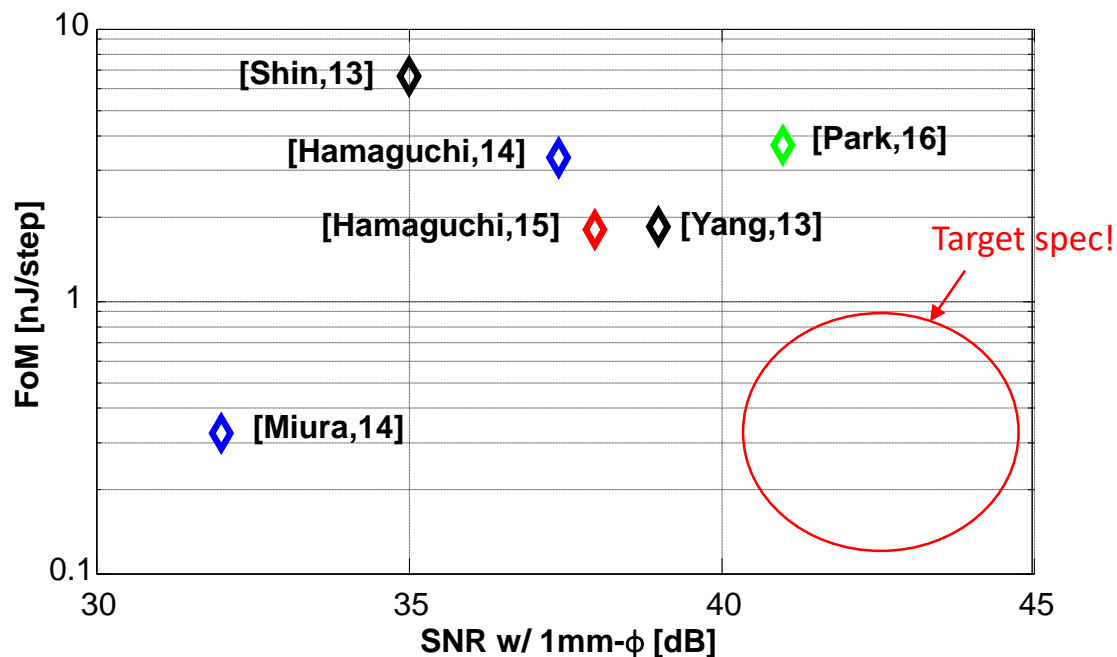
# A 6.9mW 120fps 28×50 Capacitive Touch Sensor for 1mm- $\phi$ Stylus Using Current-Driven $\Delta\Sigma$ ADCs

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# Motivation

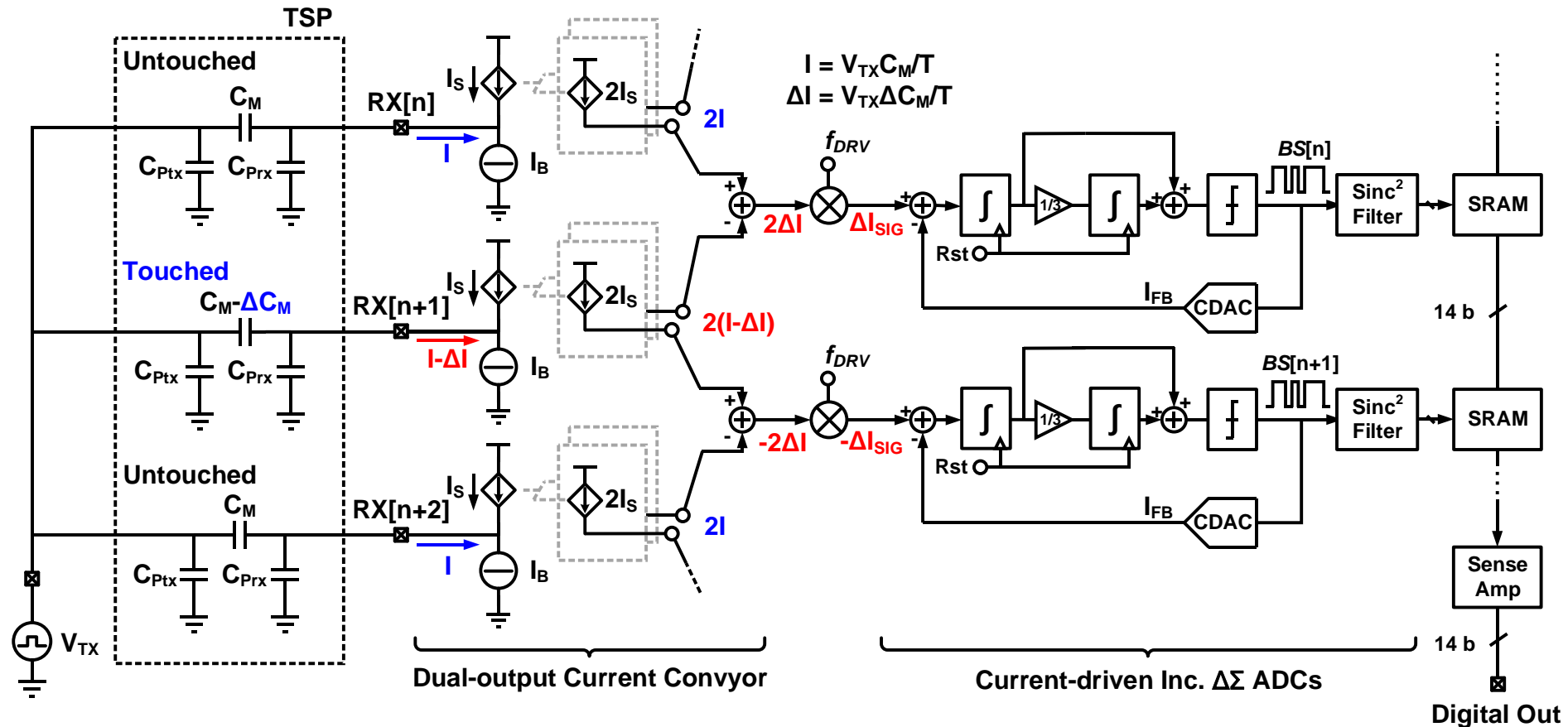


$$\text{FoM (Energy efficiency)} = \frac{\text{Power}}{2^{(\text{SNR}-1.76)/6.02} \times \text{Sensing Node} \times \text{Frame Rate}}$$



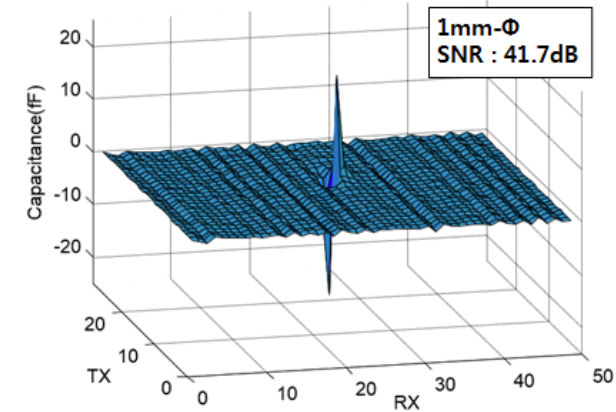
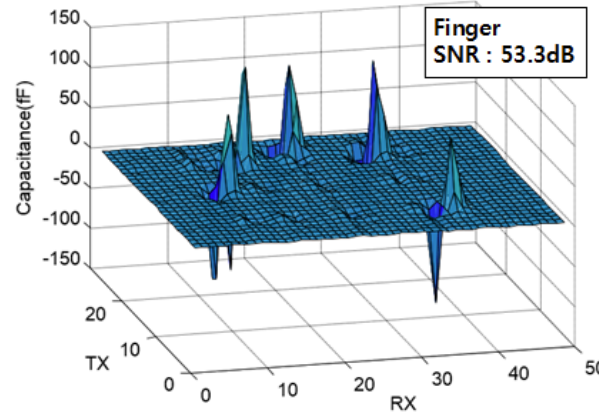
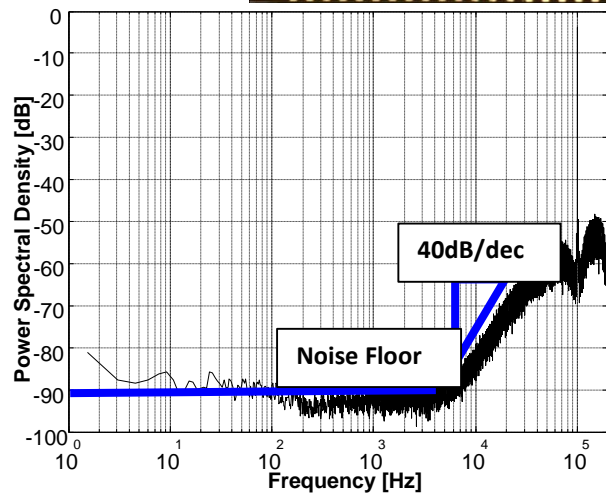
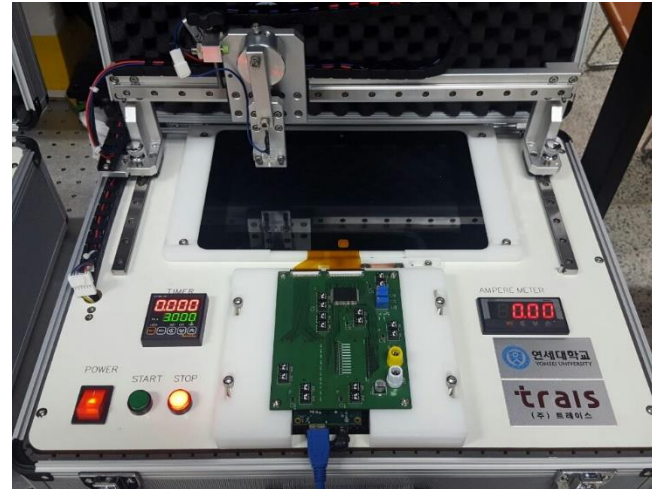
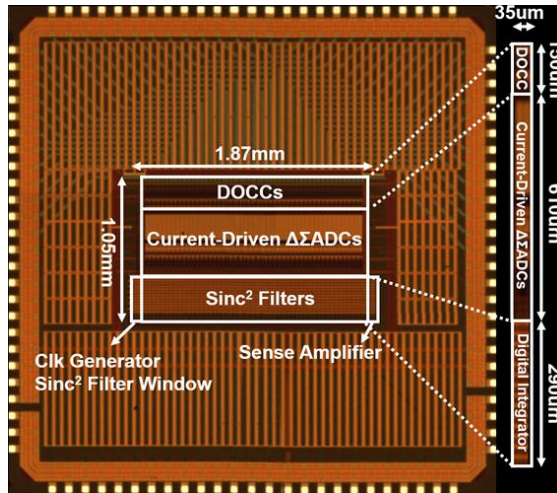
- Increased sensing channel of Touch Screen Panel (TSP) : Small signal, Increased power
- Requiring energy efficient capacitance conversion
- Target energy efficiency Figure-of-Merits (FoM) : SNR > 40dB, FoM < 1nJ/step

# Architecture



- Using dual output current conveyer AFE and 2<sup>nd</sup> order current driven  $\Delta\Sigma$  ADC
- Power saving by small current signaling and parasitic isolation
- Wide dynamic range and high SNR with oversampling ADC

# Implementation and Measurement



- 0.18 $\mu$ m CMOS process, 1.8V supply (RX), 3.3V driving voltage (TX), 28 $\times$ 50 10.1-inch TSP
- 2<sup>nd</sup> order noise shaped power spectral density of modulator
- SNR : 53.3dB (Finger), 41.7dB (1mm- $\phi$  stylus) @ 120fps

# Conclusion

		<b>This work</b>	Park ISSCC 16	Yang ISSCC 13	Hamaguchi ISSCC 14	Hamaguchi ISSCC 15
Process		<b>0.18<math>\mu</math>m</b>	0.18 $\mu$ m	0.35 $\mu$ m	0.18 $\mu$ m	85nm
SNR [dB]	Finger	<b>53.3</b>	54	-	56.6	-
	1mm- $\phi$	<b>41.7</b>	41	39	37.4	38
Supply Voltage [V]		<b>RX : 1.8 TX : 3.3</b>	RX : 2.7~3.3 TX : 3.3	RX : 3.3 TX : -	RX : 3.3/1.8 TX : 3.3	RX : 3.3/1.2 TX : 3.3
Channel		<b>RX : 50 TX : 28</b>	RX : 64 TX : 36	RX : 43 TX : 27	RX : 138 TX : 78	RX : 57 TX : 35
Frame Rate [Hz]		<b>120</b>	120	120	240	240
Power [mW]		<b>6.9</b>	94.5	18.7	559.9	56
FoM <sub>1</sub> [nJ/node]		<b>41</b>	341.8	134.2	216.7	117
FoM <sub>2</sub> [nJ/step] (1mm- $\phi$ )		<b>0.41</b>	3.73	1.84	3.58	1.8
Area [mm <sup>2</sup> ]		<b>1.96</b>	36	10.4	71.2	12.5

FoM<sub>1</sub> = Power / (# of node X Frame rate)

FoM<sub>2</sub> = Power / (2<sup>(SNR-1.76)/6.02</sup> X # of node X Frame rate)

- **Drawing only 6.9mW @ 1.8V supply voltage**
- **Achieving 0.41nJ/step FoM, 1.96mm<sup>2</sup> Area**
- **4x and 5x improvement of FoM and area on previous state-of-the-art works, respectively**